

**SCHOTTKY DIE SPECIFICATION**

TYPE: SMBR240

General Description: 40 V 2 A (Super Low Ir)

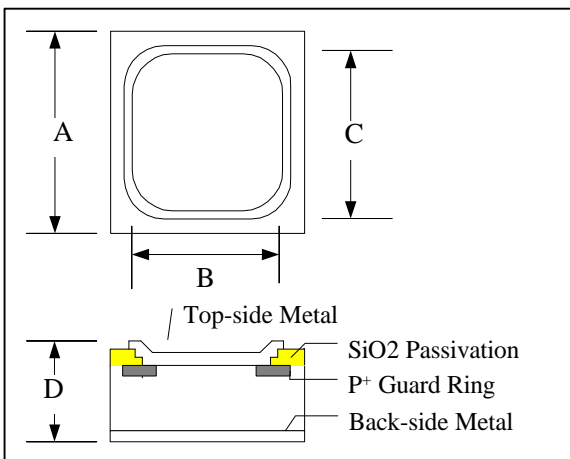
Single Anode

ELECTRICAL CHARACTERISTICS	SYM	Spec. Limit	Die Sort	UNIT
DC Blocking Voltage: Ir=1mA(for wafer form)	VRRM	40	42.5	Volt
Ir=0.5mA (for dice form)				
Average Rectified Forward Current	IFAV	2		Amp
Maximum Instantaneous Forward Voltage				
@ 2 Amperes, Ta=25°C	VF MAX	0.62	0.6	Volt
Maximum Instantaneous Reverse Voltage				
VR= 40 Volt, Ta=25°C	IR MAX	0.08	0.06	mA
Maximum Junction Capacitance @ 0V, 1MHZ	Cj MAX			pF
<b>MAXIMUM RATINGS</b>				
Nonrepetitive Peak Surge Current	IFSM	45		Amp
Operating Junction Temperature	Tj	-65 to +150		°C
Storage Temperatures	TSTG	-65 to +150		°C

Specification apply to die only. Actual performance may degrade when assembled.

MEMT does not guarantee device performance after assembly.

Data sheet information is subjected to change without notice.

**DICE OUTLINE DRAWING**


DIM	ITEM	um <sup>2</sup>	Mil <sup>2</sup>
A	Die Size	1245	49.01
B	Top Metal Pad Siz	1025	40.3
C	Passivation Seal	1203	41.1
D	Thickness (Min)	254	10
	Thickness (Max)	305	12

**PS:**

- (1) Cutting street width is around 80um(3.14mil).
- (2) Both of top-side and back-side metals are Ti/N